

SE3A THRU SE3M

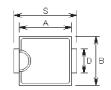
SURFACE MOUNT HIGH EFFICIENCY RECTIFIER
Reverse Voltage - 50 to 1000 Volts

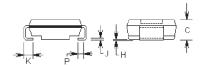
Forward Current - 3.0 Amperes

Features

- For surface mounted applications
- Low profile package
- Built-in strain relief
- Easy pick and place
- Ultrafast recovery times for high efficiency
- Plastic package has Underwriters Laboratory Flammability classification 94V-0
- High temperature soldering: 260°C/10 seconds at terminals

<u>SMC</u>





D IM E N S IO N S											
DIM	inches		m	Note							
	M in .	Max.	M in.	Max.	Note						
A	0.260	0.280	6.60	7.11							
В	0.220	0.240	5.59	6.10							
С	0.075	0.095	1.90	2 . 4 1							
D	0.115	0.121	2.92	3.07							
Н	0.0020	0.0060	0.051	0.152							
J	0.006	0.012	0.15	0.30							
К	0.030	0.050	0.76	1.27							
P	0.020 REF		0.51								
S	0.305	0.320	7.75	8.13							

Mechanical Data

• Case: SMC molded plastic

• Terminals: Solder plated solderable per

MIL-STD-750, method 2026

Polarity: Indicated by cathode bandWeight: 0.007 ounce, 0.25 gram

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	SE3A	SE3B	SE3D	SE3E	SE3G	SE3J	SE3K	SE3M	Units
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	300	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	35	70	140	210	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}	50	100	200	300	400	600	800	1000	Volts
Maximum average forward rectified current at $\rm T_L$ =75 $^{\circ}\rm C$	I _(AV)	3.0								Amps
Peak forward surge current 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method) $\rm T_A$ =55 $^\circ\rm C$	I _{FSM}	100.0							Amps	
Maximum instantaneous forward voltage at 3.0A	V _F	1.0 1.3			.3	1.5 1.7		.7	Volts	
$\begin{array}{ccc} \text{Maximum DC reverse current} & \text{T}_{\underline{A}}\text{=}25^{\circ}\text{C} \\ \text{at rated DC blocking voltage} & \text{T}_{\underline{A}}^{\underline{A}}\text{=}100^{\circ}\text{C} \end{array}$	I _R	10.0 500.0							μА	
Maximum reverse recovery time (Note 1) T_j =25 $^{\circ}$ C	T _{rr}	50.0 100.0						nS		
Typical junction capacitance (Note 2)	C _J	75.0						50.0		ρF
Maximum thermal resistance (Note 3)	R _{⊎JL}	15							°C/W	
Operating and storage temperature range	T _J , T _{STG}	-50 to +150							$^{\circ}$ C	

Notes:

- (1) Reverse recovery test conditions: I_F=0.5A, I_R=1.0A, I_R=0.25A
- (2) Measured at 1.0MHz and applied reverse voltage of 4.0 volts
- (3) 8.0mm² (0.013mm thick) land areas

RATINGS AND CHARACTERISTIC CURVES

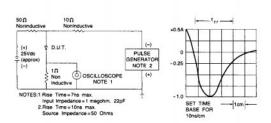


FIG. 1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

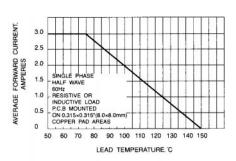


FIG. 2 - MAXIMUM AVERAGE FORWARD CURRENT RATING

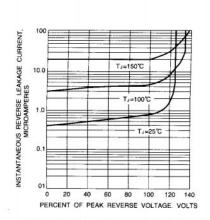


FIG. 3-TYPICAL REVERSE CHARACTERISTICS

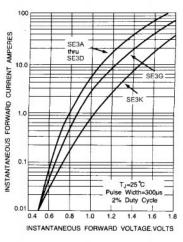


FIG. 4 - TYPICAL FORWARD CHARACTERISTICS

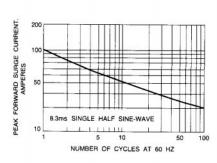


FIG. 5 – MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

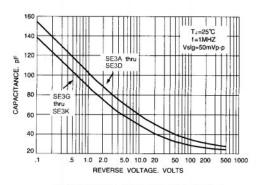


FIG. 6 - TYPICAL JUNCTION CAPACITANCE